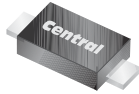


CMJ0130
THRU
CMJH180

**SURFACE MOUNT SILICON
CURRENT LIMITING DIODE**



SOD-123FL CASE



www.centra-semi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMJ0130 series types are silicon field effect current regulator diodes designed for applications requiring a constant current over a wide voltage range. These devices are manufactured in the epoxy molded, low profile SOD-123FL case. Special selections of I_P (regulator current) are available for critical applications.

MARKING: SEE MARKING CODES ON ELECTRICAL CHARACTERISTICS TABLE

FEATURES:

- High Reliability
- Superior Lot to Lot Consistency
- Special Selections Available
- Leaded Devices Available

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Operating Voltage (CMJ0130 THRU CMJ5750)

Peak Operating Voltage (CMJH080 THRU CMJH180)

Power Dissipation

Operating and Storage Junction Temperature

Thermal Resistance

SYMBOL

P_{OV}

P_{OV}

P_D

T_J, T_{stg}

θ_{JA}

100

50

500

-65 to +150

250

UNITS

V

V

mW

$^\circ\text{C}$

$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

Type	Regulator Current (Note 1)			Minimum Dynamic Impedance	Minimum Knee Impedance	Maximum Limiting Voltage	Temperature Coefficient (Note 2)	Marking Code
	$I_P @ V_T=25V$			$Z_T @ V_T=25V$	$Z_K @ V_K=6.0V$	$V_L @ I_L=0.8 \times I_P \text{ MIN}$	TC	
	MIN mA	NOM mA	MAX mA	$M\Omega$	k Ω	V	%/ $^\circ\text{C}$	
CMJ0130	0.05	0.13	0.21	6.0	2,000	0.6	+2.10 to +0.10	101
CMJ0300	0.20	0.31	0.42	4.0	1,000	0.8	+0.40 to -0.20	301
CMJ0500	0.40	0.515	0.63	2.0	500	1.1	+0.15 to -0.25	501
CMJ0750	0.60	0.76	0.92	1.0	200	1.4	0.0 to -0.32	701
CMJ1000	0.88	1.1	1.32	0.65	100	1.7	-0.10 to -0.37	102
CMJ1500	1.28	1.5	1.72	0.45	70	2.0	-0.13 to -0.40	152
CMJ2000	1.68	2.0	2.32	0.35	50	2.3	-0.15 to -0.42	202
CMJ2700	2.28	2.69	3.1	0.30	30	2.7	-0.18 to -0.45	272
CMJ3500	3.0	3.55	4.1	0.25	20	3.2	-0.20 to -0.47	352
CMJ4500	3.9	4.5	5.1	0.20	10	3.7	-0.22 to -0.50	452
CMJ5750	5.0	5.75	6.5	0.05	5.0	4.5	-0.25 to -0.53	562
CMJH080	6.56	8.2	9.84	0.32	15	3.1	-0.25 to -0.45	822
CMJH100	8.0	10	12	0.17	6.0	3.5	-0.25 to -0.45	103
CMJH120	9.6	12	14.4	0.08	3.0	3.8	-0.25 to -0.45	123
CMJH150	12	15	18	0.03	2.0	4.3	-0.25 to -0.45	153
CMJH180	16	18	20	0.02	1.8	4.6	-0.25 to -0.45	183

Notes: 1) Pulsed Method: Pulse Width (ms) = 27.5 divided by $I_P \text{ NOM (mA)}$

2) The Temperature Coefficient is measured between +25 $^\circ\text{C}$ and +50 $^\circ\text{C}$.

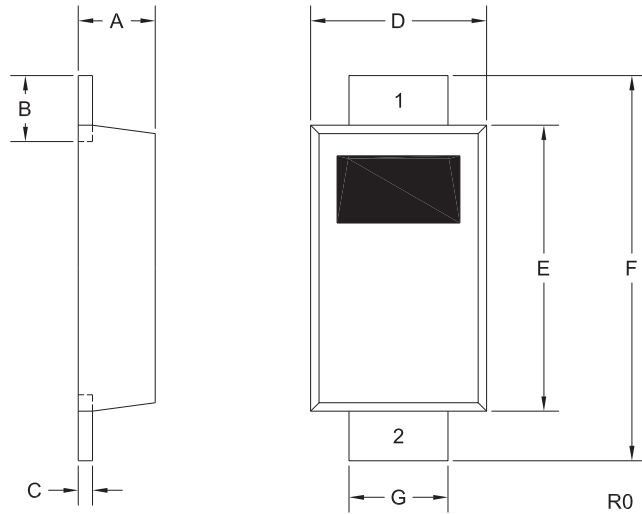
R2 (5-October 2010)

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SOD-123FL CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Cathode
- 2) Anode

MARKING: SEE ELECTRICAL
CHARACTERISTICS TABLE

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.024	0.031	0.60	0.80
B	0.020	0.028	0.50	0.70
C	0.003	0.007	0.08	0.18
D	0.059	0.067	1.50	1.70
E	0.094	0.110	2.40	2.80
F	0.130	0.146	3.30	3.70
G	0.031	0.039	0.80	1.00

SOD-123FL (REV:R0)

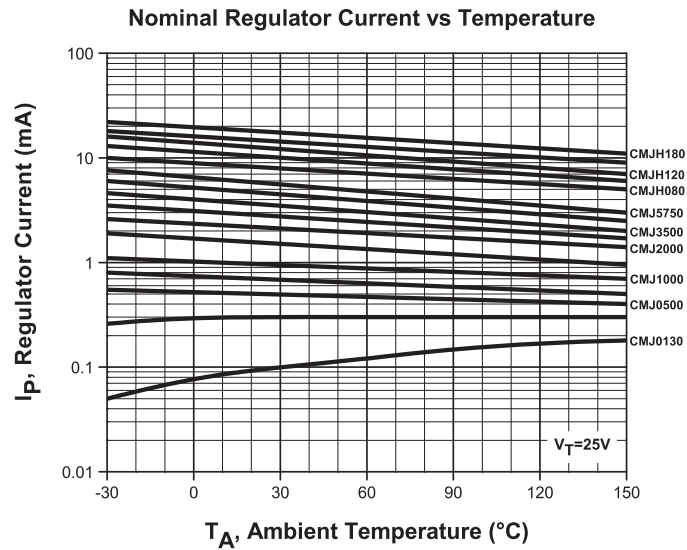
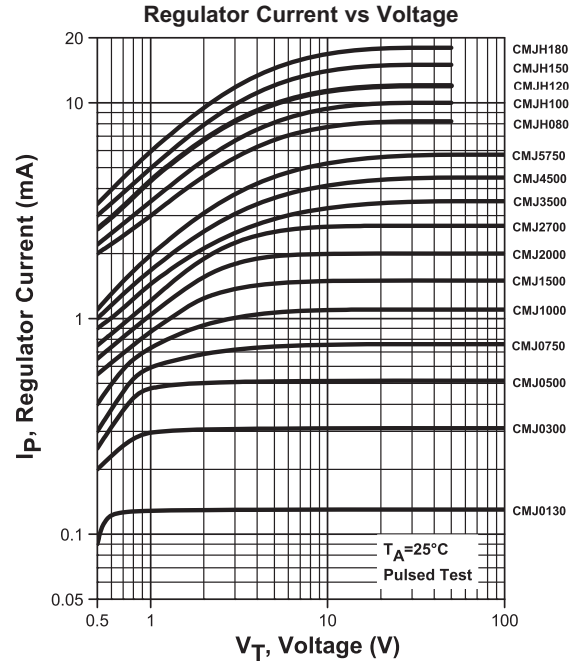
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SURFACE MOUNT SILICON
CURRENT LIMITING DIODE

TYPICAL ELECTRICAL CHARACTERISTICS



R2 (5-October 2010)